

FRED Pt® Gen 5 Ultrafast Rectifier Diode, 1200 V, 120 A



PRIMARY CHARACTERISTICS						
V _R	1200 V					
V _F (typical) at 60 A, per diode	1.99 V					
t _{rr} (typical) at 60 A, per diode	71 ns					
I _{F(DC)} per module at T _C = 85 °C	120 A					
Туре	Modules - diode FRED Pt®					
Package	SOT-227					
Circuit configuration	Two separate diodes, antiparallel pin-out					

FEATURES

- Ultrafast and optimized Q_{rr}
- Best in class forward voltage drop and switching losses trade off



- · Optimized for high speed operation
- 175 °C maximum operating junction temperature
- · Electrically isolated base plate
- Large creepage distance between terminal
- · Simplified mechanical designs, rapid assembly
- · Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, the VS-U5FH120FA120 is the right choice for high frequency converters, both soft switched / resonant. The semiconductor in the SOT-227 package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters, and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Cathode to anode voltage	V_R		1200	V		
Continuous forward current per diode	I _F	T _C = 85 °C	60	۸		
Single pulse forward current per diode	I _{FSM}	T _J = 25 °C	340	Α		
Maximum power dissipation per module	P _D	T _C = 85 °C	261	W		
RMS isolation voltage	V _{ISOL}	Any terminal to case, t = 1 min	2500	V		
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	IBOL TEST CONDITIONS MIN. TYP. MAX.		UNITS		
Cathode to anode breakdown voltage	V_{BR}	I _R = 100 μA	1200	-	-	
Forward voltage	V _{FM}	I _F = 60 A	-	1.99	2.5	V
		I _F = 60 A, T _J = 150 °C	-	1.74	-	
		V _R = 1200 V	-	0.4	80	
Reverse leakage current	I _{RM}	$T_J = 125 ^{\circ}\text{C}, V_R = 1200 \text{V}$	-	79	-	μΑ
		$T_J = 150 ^{\circ}\text{C}, V_R = 1200 \text{V}$	-	255	-	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Develope receivementime	T _J = 25 °C		-	71	-		
Reverse recovery time	t _{rr}	T _J = 125 °C	$I_F = 60 \text{ A},$ $di_F/dt = 1000 \text{ A/}\mu\text{s},$ $V_R = 800 \text{ V}$	-	114	-	ns
Dook roopyony gurrant	I _{RRM}	T _J = 25 °C		-	34	-	Α
Peak recovery current		T _J = 125 °C		-	53	-	7 ^
Reverse recovery charge	0	T _J = 25 °C		-	2.3	-	μC
	Q_{rr}	T _J = 125 °C		-	5.5	-	
Junction capacitance	C _T	V _R = 1200 V		-	22.5	=	pF

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance junction to case, per diode			-	-	0.69	
Thermal resistance junction to case, per module	R _{thJC}		-	-	0.345	°C/W
Thermal resistance case to heatsink, per module	R _{thCS}	Flat, greased surface	-	0.05	-	
Weight			-	30	=	g
Manusting toyons		Torque per diode	-	-	1.1 (9.7)	Nm (lbf.in)
Mounting torque		Torque to heatsink	-	-	1.8 (15.9)	Nm (lbf.in)
Case style				SO	Γ-227	

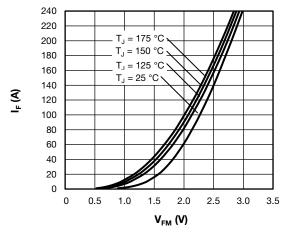


Fig. 1 - Typical Forward Voltage Drop Characteristics

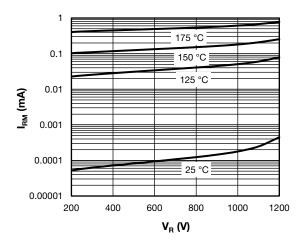


Fig. 2 - Typical Values of Reverse Current



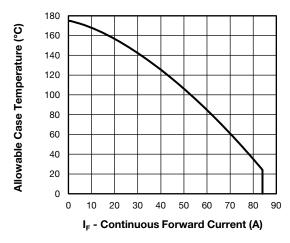


Fig. 3 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Diode)

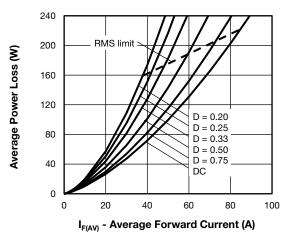


Fig. 4 - Average Power Loss vs. Average Forward Current

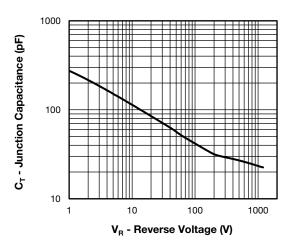


Fig. 5 - Junction Capacitance vs. Reverse Voltage

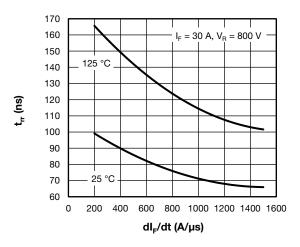


Fig. 6 - Diode Reverse Recovery Time vs. dI_Fdt

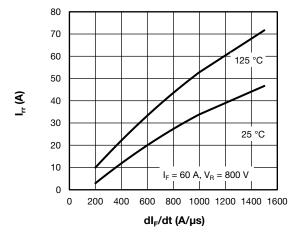


Fig. 7 - Diode Reverse Recovery Current vs. dI_Fdt

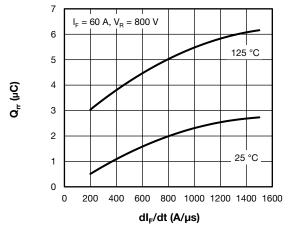


Fig. 8 - Diode Reverse Recovery Charge vs. dl_Fdt

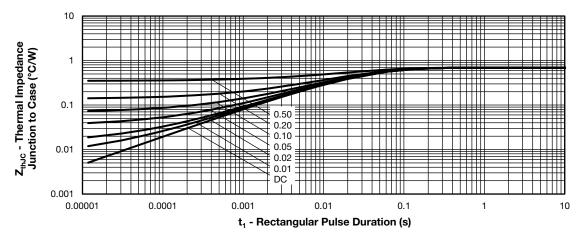


Fig. 9 - Maximum Thermal Impedance Junction to Case

ORDERING INFORMATION TABLE

- 1 Vishay Semiconductors product
- U5F = Gen 5 FRED Pt® family
- 3 H = Ultrafast FRED Pt® diode
- Current rating per module (120 = 120 A)
- 5 E = circuit configuration (two separate diodes, antiparallel pin-out)
- 6 Package indicator (SOT-227 standard insulated base)
- 7 Voltage rating (120 = 1200 V)

CIRCUIT CONFIGURATION				
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING		
Two separate diodes, antiparallel pin-out	E	Lead Assignment 40 10 2		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95423</u>				
Packaging information	www.vishay.com/doc?95425			

SOT-227 Generation 2

DIMENSIONS in millimeters (inches)





Note

· Controlling dimension: millimeter



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